

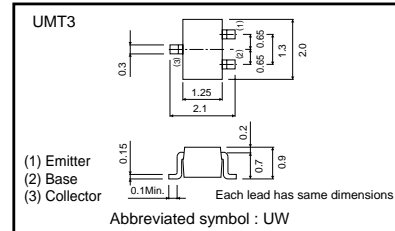
# Medium power transistor (30V, 0.5A)

## 2SC5729

### ●Features

- 1) High speed switching. ( $T_f$ : Typ.: 50ns at  $I_c = 500\text{mA}$ )
- 2) Low saturation voltage, typically  
(Typ.: 150mV at  $I_c = 100\text{mA}$ ,  $I_B = 10\text{mA}$ )
- 3) Strong discharge power for inductive load and capacitance load.
- 4) Complements the 2SA2047

### ●External dimensions (Units : mm)



### ●Applications

Small signal low frequency amplifier  
High speed switching

### ●Structure

NPN Silicon epitaxial planar transistor

### ●Packaging specifications

Type	Package	Taping
	Code	T106
	Basic ordering unit (pieces)	3000
2SC5729		○

### ●Absolute maximum ratings ( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Limits	Unit
Collector-base voltage	$V_{CB0}$	30	V
Collector-emitter voltage	$V_{CE0}$	30	V
Emitter-base voltage	$V_{EB0}$	6	V
Collector current	$I_c$	0.5	A
	$I_{cP}$	1.0	A <sup>*1</sup>
Power dissipation	$P_c$	200	mW <sup>*2</sup>
Junction temperature	$T_j$	150	$^\circ\text{C}$
Range of storage temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$

\*1  $P_w = 10\text{ms}$

\*2 Each terminal mounted on a recommended land.

Transistor

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV <sub>CEO</sub>	30	-	-	V	I <sub>c</sub> =100μA
Collector-emitter breakdown voltage	BV <sub>CBO</sub>	30	-	-	V	I <sub>c</sub> =1mA
Emitter-base breakdown voltage	BV <sub>EBO</sub>	6	-	-	V	I <sub>E</sub> =100μA
Collector cut-off current	I <sub>CB0</sub>	-	-	1.0	μA	V <sub>CB</sub> =20V
Emitter cut-off current	I <sub>EBO</sub>	-	-	1.0	μA	V <sub>EB</sub> =4V
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	-	150	300	mV	I <sub>c</sub> =100mA, I <sub>b</sub> =10mA
DC current gain	h <sub>FE</sub>	120	-	390	-	V <sub>CE</sub> =2V, I <sub>c</sub> =50mA
Transition frequency	f <sub>T</sub>	-	300	-	MHz	V <sub>CE</sub> =10V, I <sub>E</sub> =-100mA, f=10MHz
Collector output capacitance	C <sub>ob</sub>	-	5	-	pF	V <sub>CB</sub> =10V, I <sub>E</sub> =0A, f=1MHz
Turn-on time	T <sub>on</sub>	-	40	-	ns	I <sub>c</sub> =500mA
Storage time	T <sub>stg</sub>	-	120	-	ns	I <sub>b1</sub> =50mA
Fall time	T <sub>f</sub>	-	50	-	ns	I <sub>b2</sub> =-50mA
						V <sub>CC</sub> ≈25V

●h<sub>FE</sub> RANK

Q	R
120-270	180-390

●Electrical characteristic curves

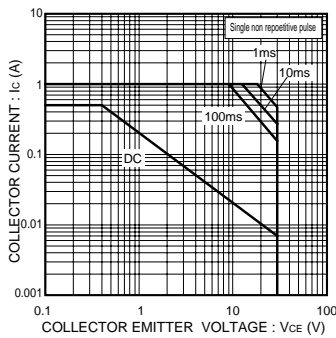


Fig.1 Safe operating area

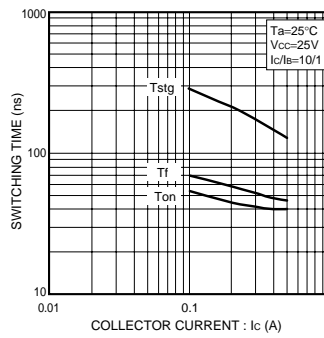


Fig.2 Switching Time

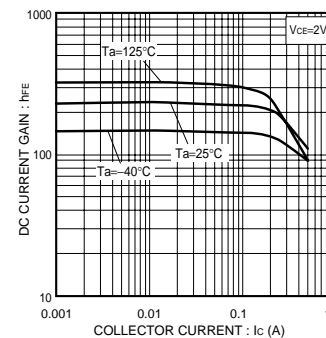


Fig.3 DC current gain vs. collector current

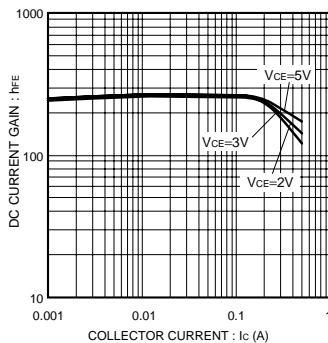


Fig.4 DC current gain vs. collector current

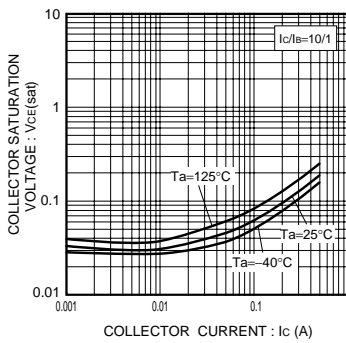


Fig.5 Collector-emitter saturation voltage vs. collector current

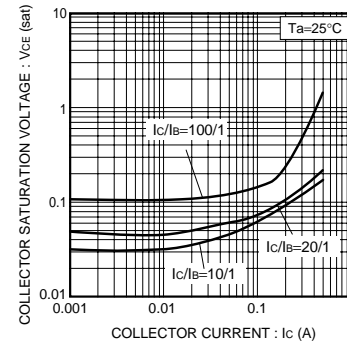


Fig.6 Collector-emitter saturation voltage vs. collector current

Transistor

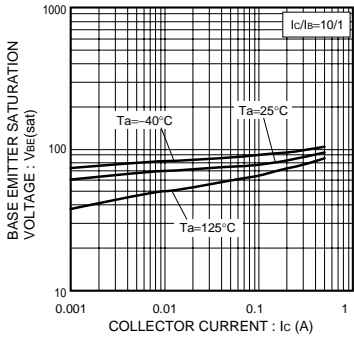


Fig.7 Base-emitter saturation voltage vs. collector current

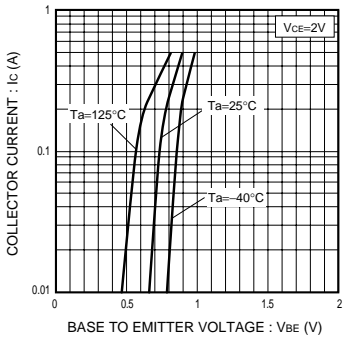


Fig.8 Ground emitter propagation characteristics

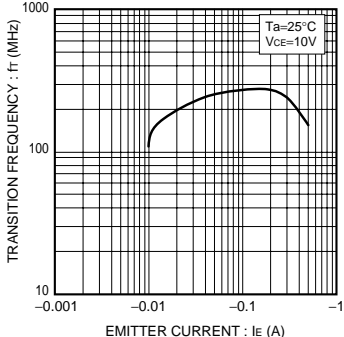


Fig.9 Transition frequency

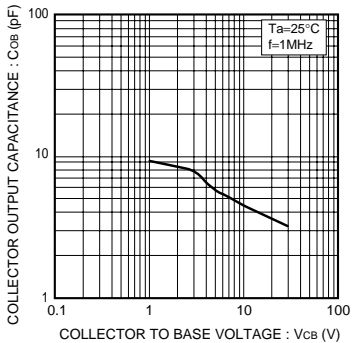
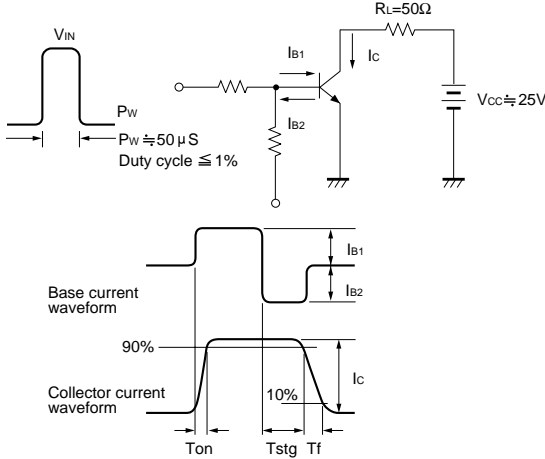


Fig.10 Collector output capacitance

●Switching characteristics measurement circuits



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